

Dynamical Franz-Keldysh effect

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We introduce and analyze the properties of dynamical Franz-Keldysh effect, i.e. the change of density-of-states, or absorption spectra, of semiconductors under the influence of *time-dependent* electric fields. In the case of a harmonic time-dependence, we predict the occurrence of significant fine structure, both below and above the zero-field band-gap, which should be experimentally observable.

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Almost forty years ago Franz [1] and Keldysh [2] pointed out that static electric fields modify the linear optical properties of bulk semiconductors near the optical absorption edge: the absorption coefficient becomes finite (though small) for photon energies below the band gap, and that the absorption coefficient shows oscillations for energies above the band gap. Studies of this kind regained importance with the development of quantum confined semiconductor structures, and a large body of both experimental and theoretical knowledge has been developed since mid 80's [3]. The purpose of this Letter is to point out that the absorption curve develops additional structure when the sample is placed in a strong ac-field, such as generated by a free-electron laser. As we shall demonstrate below, the zero-field density of states splits into replicas, with field-dependent shifts and time-dependent amplitudes. In contrary to the static case, where it is sufficient to solve a simple Schrödinger equation, the time-dependent case necessitates the use of a more advanced formalism; in the present case we apply nonequilibrium Green function techniques. In order to present our predictions in a clear-cut manner, we have stripped the model calculation from complications that may be present in real samples, such as scattering due to sample nonidealities and phonons, or excitonic effects. Thus, the main motivation of the present *analytic* study is to point out the existence of an effect, and not address the quantitative details, which can be treated properly only with a full-scale numerical calculation based on, for example, solution of the semiconductor Bloch equations [4].

The calculation of the electroabsorption coefficient $\alpha(\omega)$ for free carriers is discussed in text-books [5], and the result can be expressed as

$$\alpha(\omega) = \alpha_0 \sum_n |\psi_n(\mathbf{r}=0)|^2 \delta(E_n - \hbar\omega), \quad (1)$$

where ψ_n and E_n are the eigenfunctions and eigenvalues of the electron-hole pair Schrödinger equation, respectively. The important feature of Eq.(1) for our purposes is that it states that the absorption coefficient is essentially given by the joint density-of-states, $\alpha(\omega) \simeq \rho(\omega) \equiv$

$\sum_n \delta(\omega - E_n)$. In equilibrium many-body theory one can express the density-of-states in terms of the imaginary part of the retarded Green function, or, equivalently, by the spectral function. The important property of the nonequilibrium theory of Kadanoff-Baym [6] and Keldysh [7] is that in nonequilibrium the diagrammatic structure of the perturbation theory is the same as in equilibrium, with the proviso that real-time integrals must be generalized to a complex contour [8]. The upshot is that the nonequilibrium retarded Green function can be calculated from a Dyson equation which is formally identical to the equilibrium case. Thus, we can analyze the electroabsorption properties of a semiconductor in an applied time-dependent electric field by evaluating

$$\begin{aligned} \rho(\omega, T) &= -\frac{1}{\pi} \sum_{\mathbf{k}} \text{Im} \tilde{G}^r(\mathbf{k}, \omega, \mathbf{T}) \\ &= \frac{1}{2\pi} \sum_{\mathbf{k}} \tilde{A}(\mathbf{k}, \omega, \mathbf{T}). \end{aligned} \quad (2)$$

Eq.(2) introduces a *generalized density-of-states* function, which is time-dependent due to the external electric field. Whether a measurement probes $\rho(\omega, T)$ or perhaps its suitably weighted time-average depends on the various time-scales of the particular experimental set-up; here we focus on the full time-dependence, because it contains most information. In (2) we also introduce the gauge-invariant form $\tilde{G}^r(\mathbf{k}, \omega, \mathbf{T})$ of the two-time Green function $G^r(\mathbf{x}, \mathbf{x}', t, t')$, which we calculate via its Dyson equation. Effects due to interactions can be taken into account by introducing a suitable self-energy. Under certain conditions the Dyson equation for the retarded Green function may involve particle densities; in this case one must also solve the appropriate quantum kinetic equation for the distribution function. However, this problem is not addressed in the present paper.

In an actual calculation the longitudinal electric field must be introduced by using some explicit gauge; however predictions for observables must clearly be gauge-independent, and hence the gauge-invariant formulation is essential. In general, the transformation to gauge invariant variables occurs via [9]

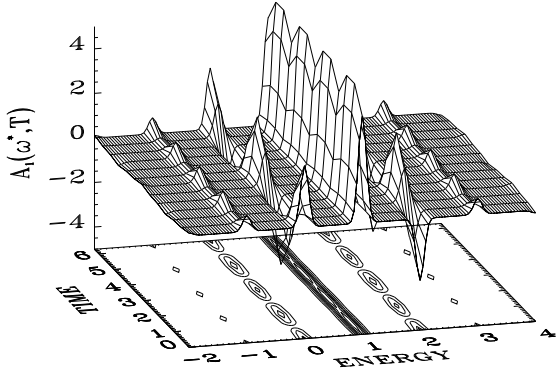


FIG. 1. The function $\tilde{A}_1$ as a function of the variable $\omega^* = (\omega - \epsilon_k)/\Omega$. The field strength is given by $\omega_F/\Omega = 1$. The δ -function singularities of $\tilde{A}_1$ have been broadened for illustrative purposes

$$\tilde{G}^r(p, X) = \int d^4 q G^r(q, X) \times \exp\left(iq_\mu [p_\mu + \int_{-1/2}^{1/2} d\lambda A_\mu(X + \lambda q)]\right), \quad (3)$$

where we have used the Einstein summation convention and a “covariant” notation, where four-momenta and coordinates are given by $p \equiv (\omega, \mathbf{k})$, $q \equiv (\tau, \mathbf{r}) = (t - t', \mathbf{x} - \mathbf{x}')$, and $X \equiv (T, \mathbf{R}) = ([t + t']/2, [\mathbf{x} + \mathbf{x}']/2)$. Correspondingly, the potentials defining the electric field are contained in $A \equiv (\phi, \mathbf{A})$.

In our calculation of the density-of-states for a uniform but time-dependent field it is convenient to describe the electric field with a vector potential, $\mathbf{A}(t) = -\mathbf{E} \sin(\Omega t)/\Omega$ (here we restrict ourselves to harmonic time-dependence). The retarded Green function satisfies [10]

$$\left\{ i \frac{\partial}{\partial t} - \epsilon[\mathbf{p} - \mathbf{A}(t)] \right\} G^r(\mathbf{p}, t, t') = \delta(t - t'). \quad (4)$$

Using (3) Eq.(4) immediately leads to the gauge invariant spectral function $\tilde{A} = i(\tilde{G}^r - \tilde{G}^a)$,

$$\tilde{A}(\mathbf{k}, \omega, T) = \int d\mathbf{r} d\tau e^{i\omega\tau} \int d\mathbf{p} e^{i\mathbf{r} \cdot \mathbf{p}} \times \exp\left\{ -i \int_{T-\tau/2}^{T+\tau/2} dt_1 \epsilon[\mathbf{p} - \mathbf{A}(t_1)] \right\}, \quad (5)$$

where

$$w = \tau\omega - \mathbf{r} \cdot \mathbf{k} - \int_{T-\tau/2}^{T+\tau/2} \frac{dt_1}{\tau} \mathbf{r} \cdot \mathbf{A}(t_1). \quad (6)$$

It is illustrative to see how the static field results [11] can be recovered from Eqs.(5-6). In the limit $\Omega \rightarrow 0$ and for parabolic bands Eq.(5) reduces to

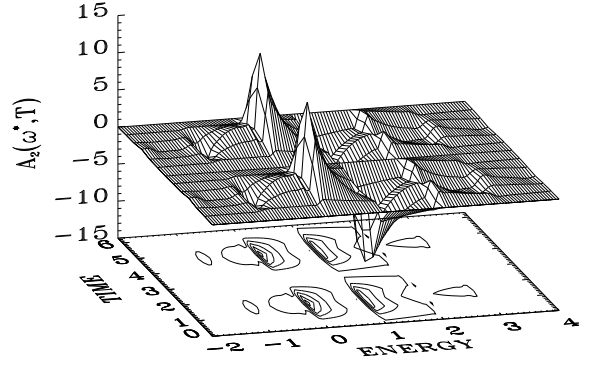


FIG. 2. The function $\tilde{A}_2$. The parameters are defined in the caption of Fig. 1.

$$A_{dc}(\mathbf{k}, \tau) = \exp[-i(\epsilon_k \tau + E^2 \tau^3/24)] \\ A_{dc}(\mathbf{k}, \omega) = (2\pi/\beta) \text{Ai}[(\epsilon_k - \omega)/\beta], \quad (7)$$

with $\beta = (\hbar^2 e^2 E^2/8m)^{1/3}$, and $\text{Ai}(x)$ is the Airy function. Evaluation of the momentum sum leads then in three dimensions to

$$\rho_{dc}^{3D}(\omega) \propto [\text{Ai}'^2(-(\omega/\Theta)) + (\omega/\Theta) \text{Ai}^2(-(\omega/\Theta))], \quad (8)$$

with $\Theta = 4^{1/3} \beta/\hbar$. Eq.(8) is the standard form for the Franz-Keldysh line-shape [5].

In the time-dependent case, one finds

$$\tilde{A}(\mathbf{k}, \omega, T) = \int d\tau \cos[(\omega - \epsilon_k - \omega_F)\tau + X(\tau) + 2Y(\tau)], \quad (9)$$

where we have introduced the notation

$$X(\tau) = \frac{\omega_F}{\Omega} \sin \Omega \tau \cos 2\Omega T \quad (10)$$

$$Y(\tau) = \frac{\omega_F}{\Omega} \frac{4 \sin^2(\Omega \tau/2) \sin^2 \Omega T}{\Omega \tau}, \quad (11)$$

and defined the field parameter $\omega_F = e^2 F^2/(4m\hbar\Omega^2)$ [12]. An explicit analytic evaluation of the integral in (9) is not possible, nor is a straightforward numerical calculation feasible due to its singular character. The singularities, however, can be isolated with analytic means, and we proceed as follows. The trigonometric identity $\cos(x+y) = \cos x - 2 \sin(x+y/2) \sin(y/2)$ allows us to write (9) as a sum of two terms, $\tilde{A} = \tilde{A}_1 + \tilde{A}_2$, where

$$\tilde{A}_1(\mathbf{k}, \omega, T) = \int d\tau \cos[(\omega - \epsilon_k - \omega_F)\tau + X(\tau)], \quad (12)$$

$$\tilde{A}_2(\mathbf{k}, \omega, T) = -2 \int d\tau \sin[(\omega - \epsilon_k - \omega_F)\tau + X(\tau) + Y(\tau)] \sin Y(\tau). \quad (13)$$

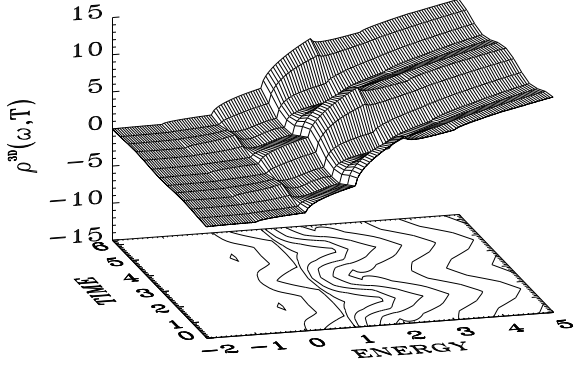


FIG. 3. Density of states, three dimensions.

The integral defining $\tilde{A}_2$ is convergent, and its numerical evaluation is straightforward. On the other hand, analytic progress can be made with $\tilde{A}_1$, which contains the aforementioned singularities. Recalling the identity $\int_{-\infty}^{\infty} dx \cos(ax - b \sin x) = 2\pi \sum_{n=-\infty}^{\infty} J_n(b) \delta(n - a)$, where J_n is the n -th order Bessel function, we finally obtain

$$\tilde{A}_1(\mathbf{k}, \omega, T) = 2\pi \sum_{n=-\infty}^{\infty} J_n\left[-\frac{\omega_F}{\Omega} \cos(2\Omega T)\right] \times \delta(\omega - \epsilon_k - n\Omega - \omega_F). \quad (14)$$

These two components $\tilde{A}_1$ and $\tilde{A}_2$ of the spectral function have quite distinct properties. The frequency sum rule is exhausted by $\tilde{A}_1$ alone, [13] *i.e.* $\int d\omega/2\pi \tilde{A}_1(\omega, T) = 1$, while $\int d\omega/2\pi \tilde{A}_2(\omega, T) = 0$. Further, the delta-function singularities of $\tilde{A}_1$ are reminiscent of *photonic side-bands* [14], however in the present case these features are shifted by the field- and frequency-dependent parameter ω_F . In the zero-field limit $\tilde{A}_1$ reduces to the field-free result $a_0(k, \omega) = 2\pi\delta(\omega - \epsilon_k)$, while $\tilde{A}_2$ vanishes. Note also that the spectral function depends *quadratically* on the electric field. This is consistent with physical intuition: since there is no preferred direction, it should not matter if the field direction is reversed, $\mathbf{E} \rightarrow -\mathbf{E}$, and thus one expects to find a spectral function that is even in the applied field. The functions $\tilde{A}_1$ and $\tilde{A}_2$ are displayed in Figs. 1 and 2, respectively.

We can use the above results to calculate a time-dependent density-of-states function $\rho(\omega, T)$. The contribution arising from $\tilde{A}_1$ is readily evaluated by using the delta-function, while $\tilde{A}_2$ requires some more work. In three dimensions we find [15]

$$\rho_1^{3D}(\omega, T) = \frac{(2m^3)^{1/2}}{2\pi^2\hbar^{5/2}} \sum_{n=-\infty}^{\lfloor \frac{\omega - \omega_F}{\Omega} \rfloor} J_n\left[-\frac{\omega_F}{\Omega} \cos(\Omega T)\right] \times (\omega - \omega_F - n\Omega)^{1/2} \quad (15)$$

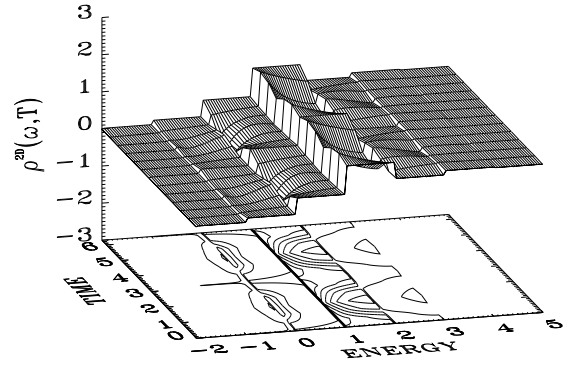


FIG. 4. Density of states, two dimensions.

and

$$\rho_2^{3D}(\omega, T) = \frac{(\pi m^3)^{1/2}}{4\pi^3\hbar^{5/2}} \int_0^\infty \frac{d\tau}{\tau^{3/2}} \sin[Y(\tau)] \times \sin[(\omega - \omega_F)\tau + X(\tau) + Y(\tau) + \pi/4]. \quad (16)$$

Here the summation over n should be cut-off at the largest integer not exceeding $[(\omega - \omega_F)/\Omega]$. A numerical example is shown in Fig. 3. The overall qualitative picture is dominated by the free-electron like square-root components generated by the photonic side-bands in $\tilde{A}_1$. At different points of time, however, the n :th side-band amplitude, which is determined by the Bessel function J_n , may change its sign, which can be seen in Fig. 3. The more detailed fine structure in $\rho^{3D}(\omega, T)$ is caused by the contribution originating from $\tilde{A}_2$.

Similar, but even more dramatic effects can be found in two dimensions where the result is

$$\rho_1^{2D}(\omega, T) = \frac{m}{2\pi\hbar^2} \sum_{n=-\infty}^{\lfloor \frac{\omega - \omega_F}{\Omega} \rfloor} J_n\left[-\frac{\omega_F}{\Omega} \cos(\Omega T)\right] \times \theta(\omega - \omega_F - n\Omega) \quad (17)$$

$$\rho_2^{2D}(\omega, T) = \frac{m}{2\pi^2\hbar^2} \int_{-\infty}^\infty \frac{d\tau}{\tau} \sin[Y(\tau)] \times \cos[(\omega - \omega_F)\tau + X(\tau) + Y(\tau)]. \quad (18)$$

The zero-field step-function reflecting the two dimensional density-of-states is split into several substeps extending to energies well below the gap, and the above threshold values are modified by additional structures, whose amplitude tends to zero for increasing energies. Just as in the three-dimensional case, the relative amplitude of the substeps changes as a function of time, and the fine structure in the energy dependence is due to $\tilde{A}_2$.

It is also of interest to examine how the time-dependent density of states depends on the field strength at a fixed frequency. The effects are most easily analyzed by examining the time-average or the density of states,

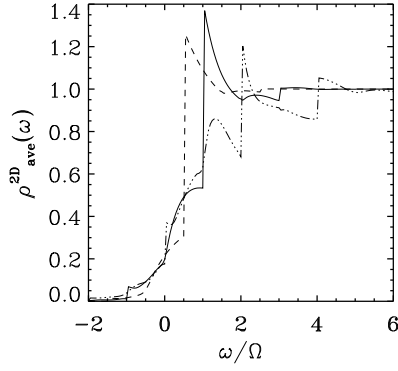


FIG. 5. Time-averaged 2-dimensional density of states (in units of zero-field density of states) for $\omega_F/\Omega = 0.5$ (dashed line), 1 (solid line), and 2 (dash-dots).

$\rho_{\text{ave}}(\omega) \equiv (\Omega/2\pi) \int_0^{2\pi/\Omega} dT \rho(\omega, T)$, and Fig. 5 shows the results of such a calculation. The following features of $\rho_{\text{ave}}(\omega)$ are of importance: (i) The main absorption edge moves to higher energies with increasing field strength; (ii) There is a significant enhancement at the absorption edge; and (iii) the range of energies where the edge is modified increases with increasing field strengths.

Finally let us comment on the observability of the predicted effects. There are several limiting factors: the spectral resolution in an absorption measurement, the available frequencies, and the maximal ac-field strengths that can be applied to the sample. From the results presented above we conclude that most favorable conditions are obtained if $\omega_F/\Omega > 1$. It would appear that this condition is most easily achieved at low frequencies. However, a small Ω implies that all the fine-structure would be confined to the immediate neighborhood of the absorption edge (in the example of Fig. 5 the fine structure extends only a few Ω 's above the edge), and not resolvable spectroscopically. Increasing Ω leads to an increased $\mathbf{E}$ in order to maintain sufficiently large ω_F/Ω . By using parameters attainable with free-electron lasers [16], $\Omega \simeq 1$ THz, $\mathbf{E} \simeq 1$ MV/m, and the GaAs effective mass, we estimate that $\omega_F/\Omega \simeq 1$. This implies that the fine-structure extends a few meV around the absorption edge, and should be observable.

In summary, we have calculated the density of states of free carriers in time-dependent fields, and find that a harmonically varying external field leads to a field and frequency dependent shift of the main absorption edge, and gives rise to fine structure (“dynamical Franz-Keldysh effect”) of observable magnitude.

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